



Automotive Division Call

hosted by Liberum

Peter Schiefer, Division President Automotive (ATV)
5 October 2020



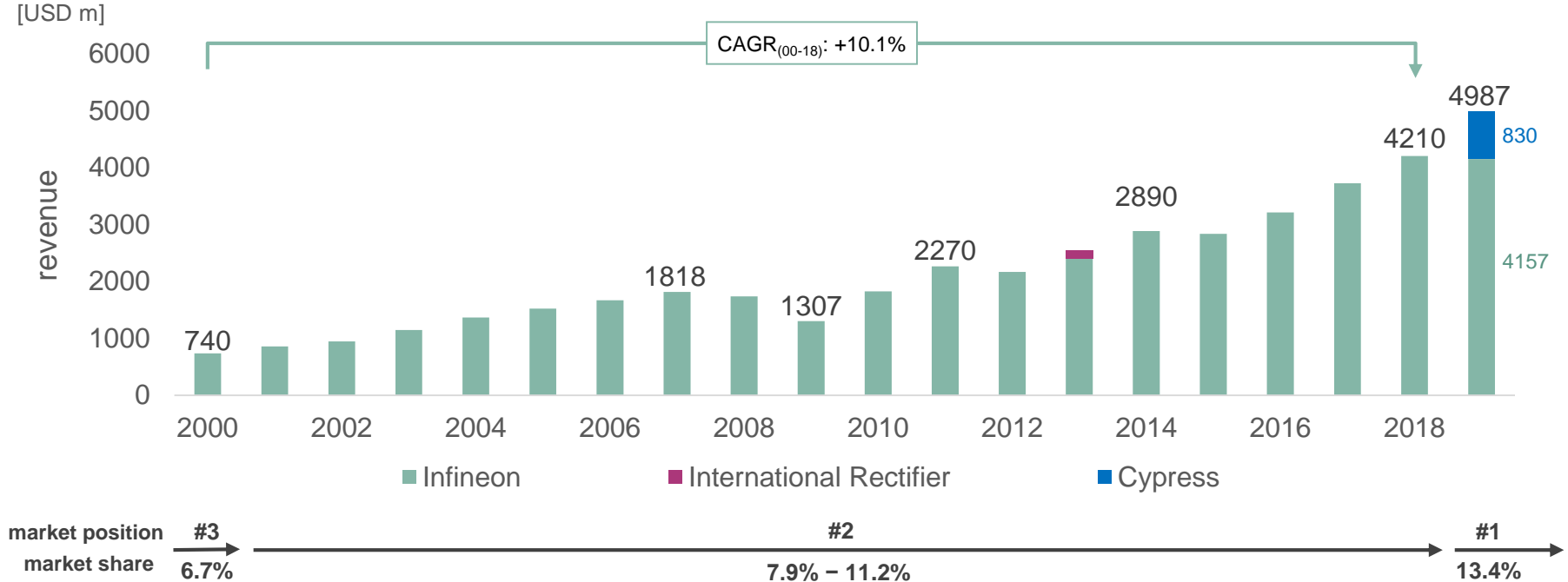


Market position and short- and mid-term outlook



Infiniteon has been growing by 10% p.a. in automotive semis over the last two decades and hence steadily gaining market share

Infineon's automotive semiconductor revenue (in USD for CY; based on market figures by Strategy Analytics)

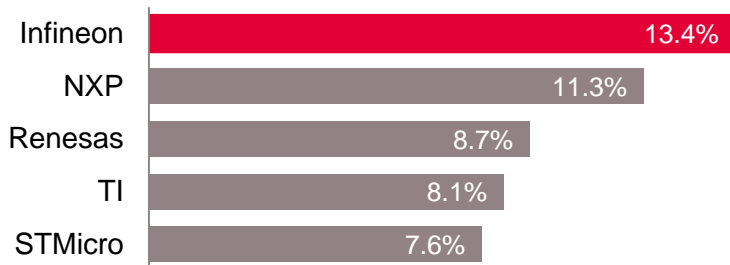


Source: Strategy Analytics: *Automotive Semiconductor Vendor Market Shares*. 2001 through 2020

Infiniteon's top market position is built on system competence based on an industry-leading product portfolio

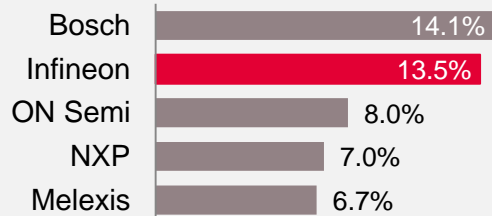


Automotive semiconductors (2019 total market: \$37.2bn)

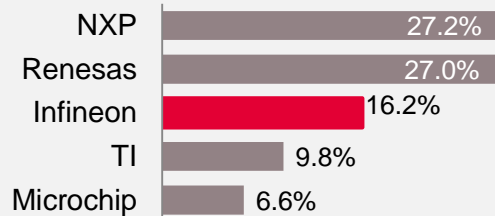


- › New #1 in the total market post acquisition of Cypress
- › Solid #1 in power despite xEV subsidies cut in China in H2 CY19
- › Undisputed #1 in automotive NOR Flash memory
- › Fostering #2 in sensors (from 10.4%_{CY12} to 13.5%_{CY19})
- › Significant market share gain in microcontroller – both organically (strong demand for AURIX™) and via Cypress acquisition

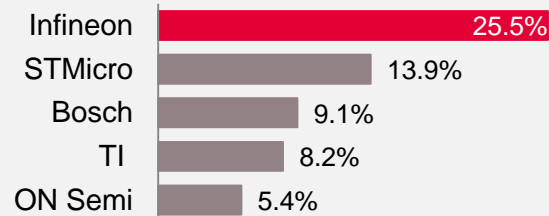
Sensors



Microcontrollers



Power semiconductors



Source: Strategy Analytics: *Automotive Semiconductor Vendor Market Shares v2*. May 2020. The market shares shown here are the combined market shares of Infineon and Cypress based on their individual figures.

Market recovery expected to continue across all regions; high demand for xEV in Europe; L1/L2/L2+ penetration on schedule

Market Outlook for Q4 CY20



Car units

- › Continued recovery of car sales and production



xEV

- › Strong momentum in Europe
- › Some recovery in the US and China



ADAS/AD

- › No major change in OEMs' plans in near-term
- › L2 growth to continue

Market Outlook for CY21

- › Y-Y recovery with unit growth at mid-teens %

- › Incentives and CO₂ regulations should keep demand high; especially in Europe
- › Improving consumer sentiment around sustainability theme
- › Steady investments in EV charging infra-structure further lowering reservation towards EVs

- › Further increase in L2 penetration expected
- › L2+ shipments at low volumes

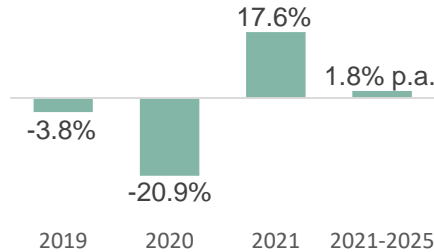
Source: Infineon; based on or includes content supplied by IHS Markit, Automotive Group: *Light Vehicle Production Forecast*. September 2020.

After nearly 20% y-y decline globally in CY20 due to COVID-19, all regions are forecast to snap back in CY21

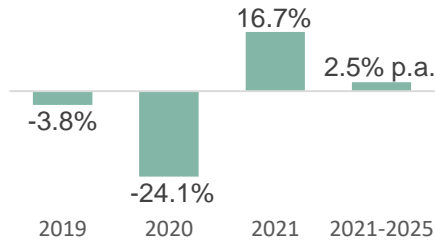


Light vehicle production (year-over-year growth)

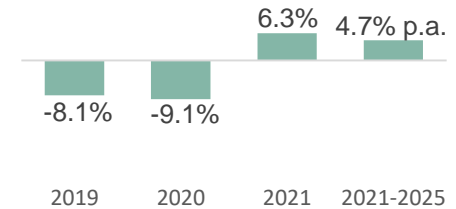
North America (16.3m units in 2019)



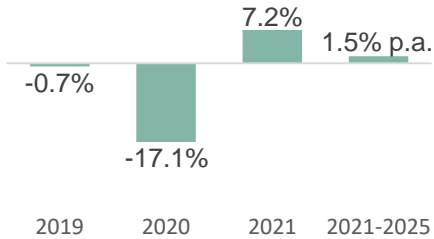
Europe (21.1m units in 2019)



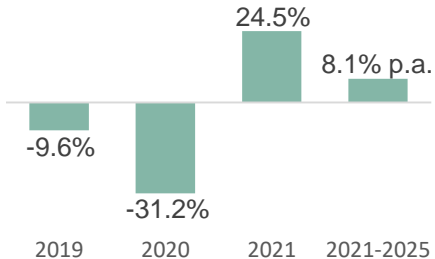
Greater China (24.7m units in 2019)



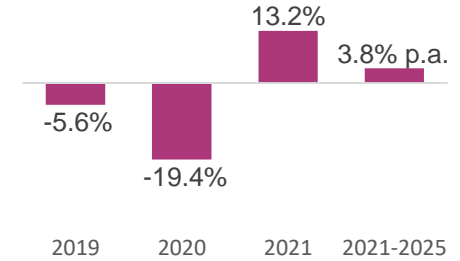
Japan / Korea (13.1m units in 2019)



RoW (13.7m units in 2019)



World (88.9m units in 2019)



Source: Based on or includes content supplied by IHS Markit, Automotive Group: *Light Vehicle Production Forecast*. September 2020.

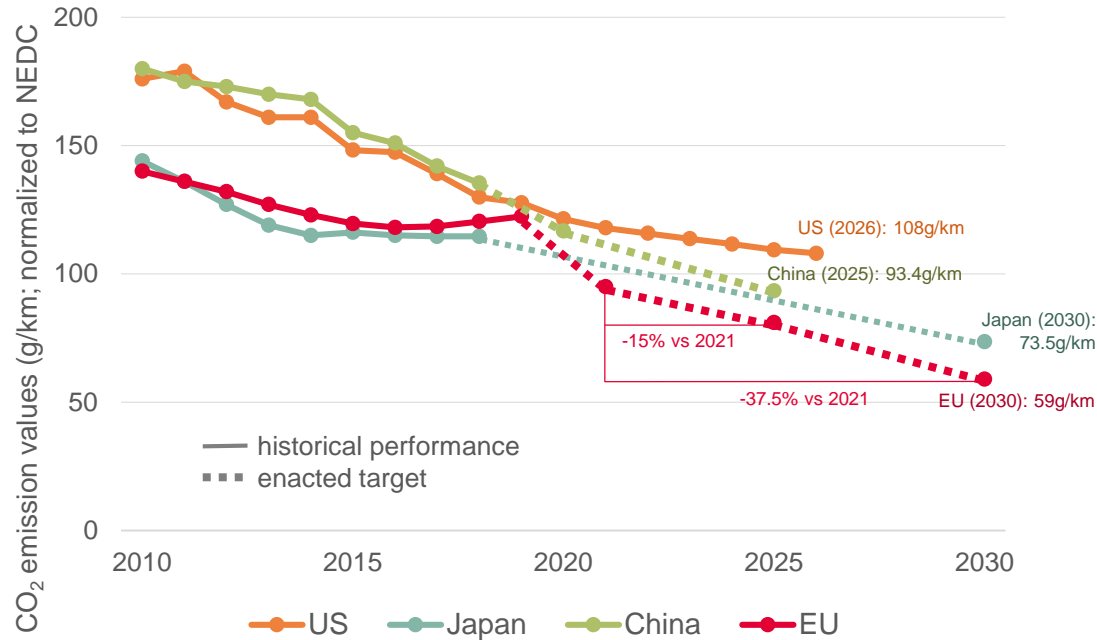


Electro-mobility



Trends toward electrification of cars remain unchanged; driven by more stringent legal guidelines

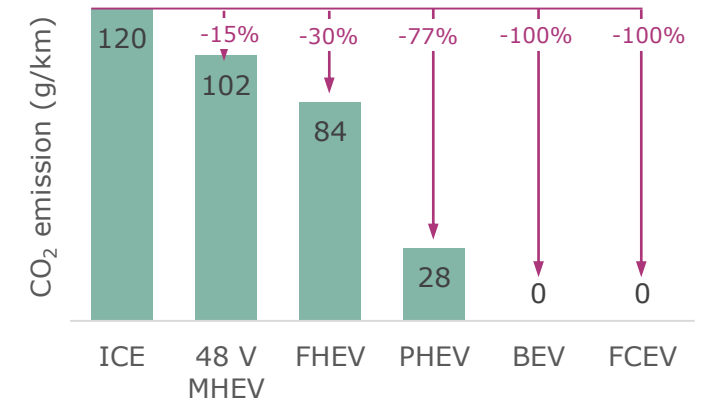
Passenger car CO₂ emission development and regional regulations



Source: The International Council on Clean Transportation (ICCT): *Passenger vehicle fuel economy*. May 2020.

CO₂ emission by degree of electrification

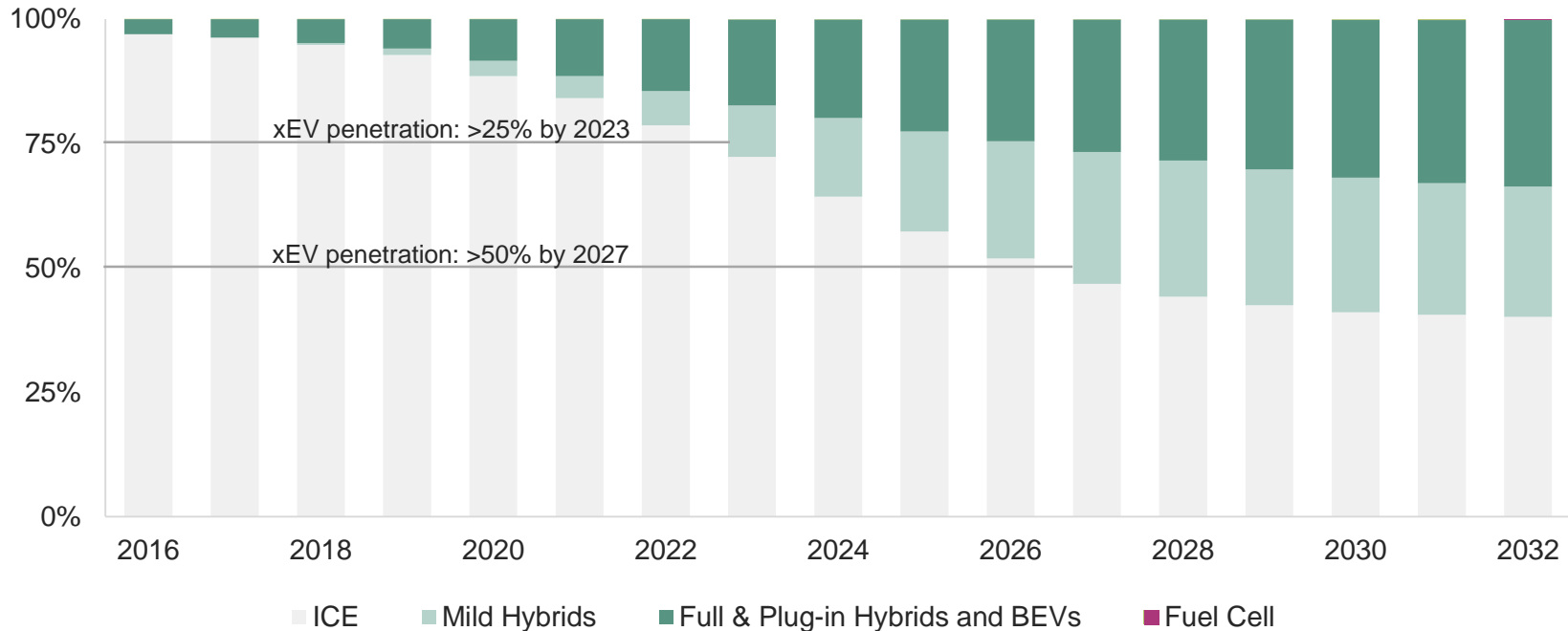
CO₂ emission: Tank-to-wheel



- › EU continues towards stringent emission standards
- › Recently, the governor of California signed an executive order mandating that all new cars to be sold in California from 2035 must be zero-emission vehicles

The longer-term trend towards xEV is unchanged; most likely even accelerating due to incentive programs and green deals

Car production by fuel type

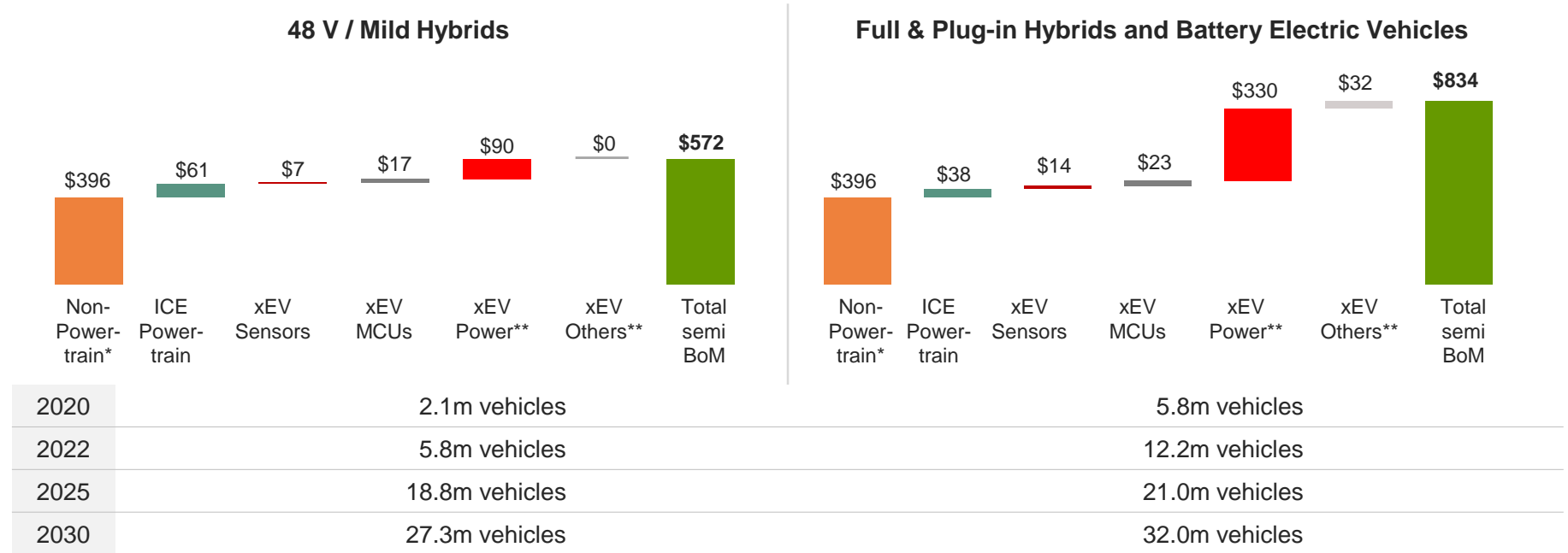


Source: Based on or includes content supplied by IHS Markit, Automotive Group: *Alternative propulsion forecast*. July 2020.

The incremental content of power semiconductors in xEV is a significant opportunity for Infineon



2020 average xEV semiconductor content by degree of electrification



* Non-Powertrain: average semiconductor content in body, chassis, safety and infotainment application segments

** "power" includes voltage regulators and ASIC; "others" include opto, small signal discretes, memory

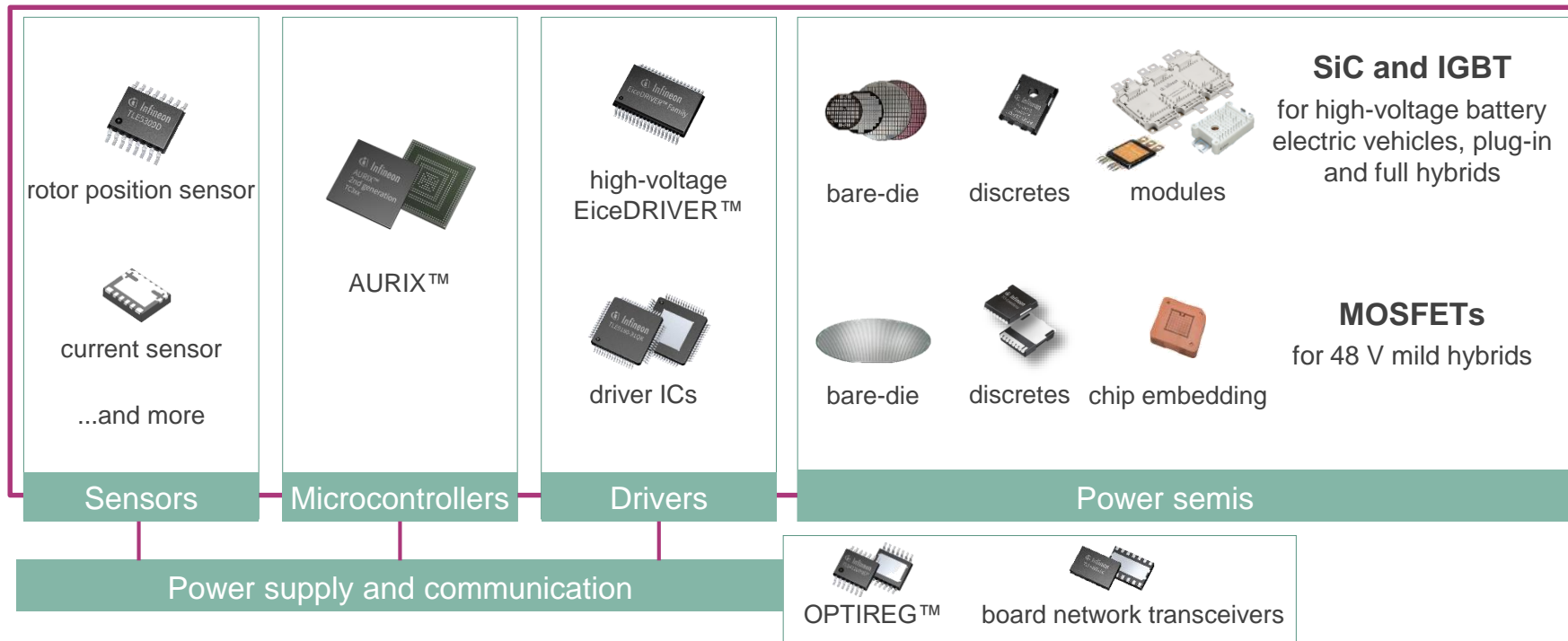
Source: Infineon; based on or includes content supplied by IHS Markit, Automotive Group: *Alternative Propulsion Forecast*. July 2020;

Strategy Analytics: *Automotive Semiconductor Demand Forecast 2018-2027* and *Automotive Sensor Demand 2018-2027*. July 2020

Infiniteon offers full system solutions addressing all xEV segments: pure EV and all types of hybrid EVs

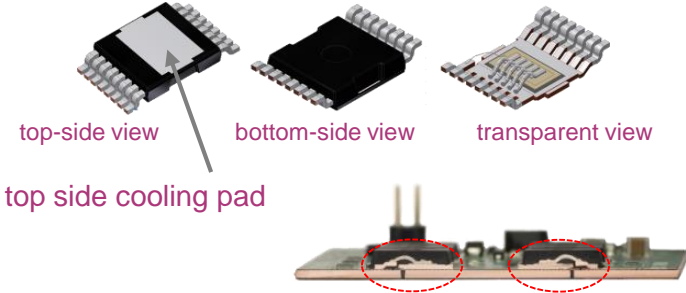
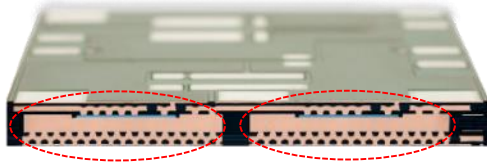


Infiniteon offers full portfolio for the control loop of an electric car



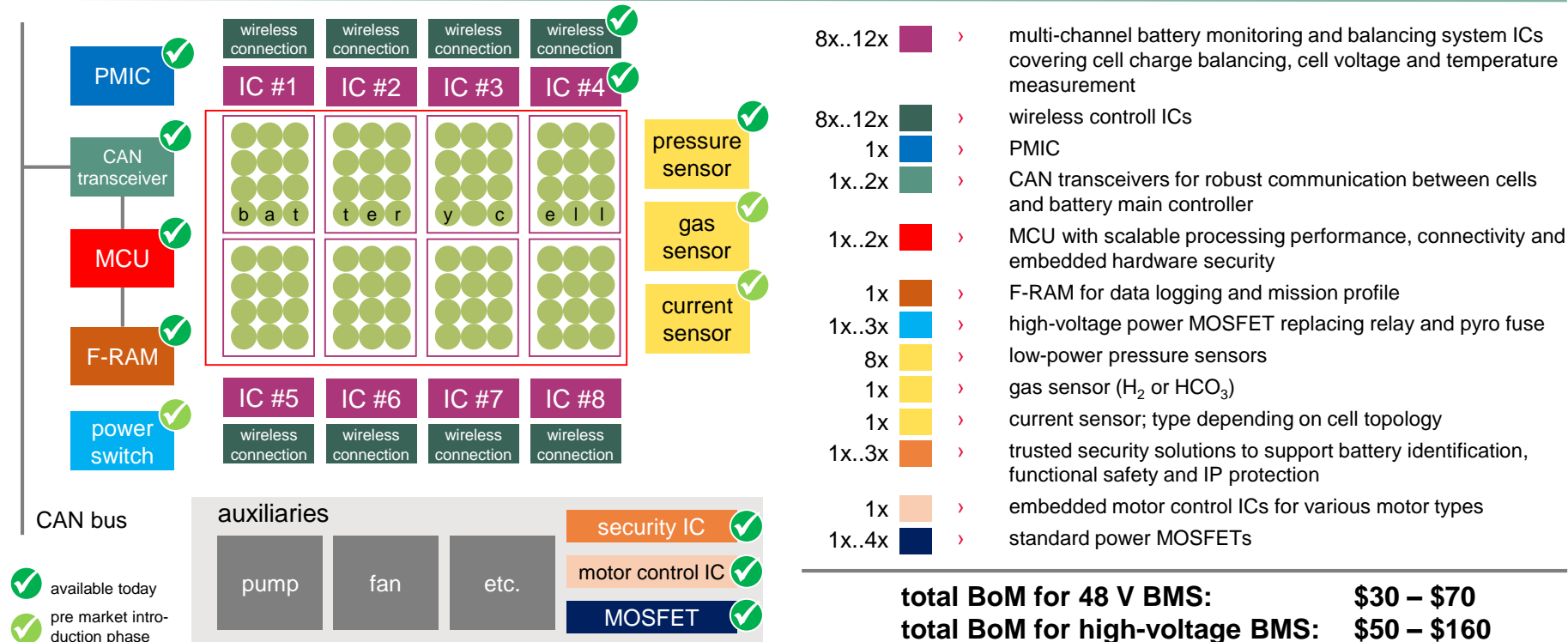
Key package innovations complement Infineon's leading position in chip technologies for 48 V systems

Key package innovations driving growth for the xEV business

| | | |
|-------------------|---|---|
| Technology | <p data-bbox="542 276 935 312">Top-side cooling package</p>  <p data-bbox="369 473 529 497">top-side view</p> <p data-bbox="604 473 784 497">bottom-side view</p> <p data-bbox="846 473 1025 497">transparent view</p> <p data-bbox="369 536 633 560">top side cooling pad</p> <p data-bbox="465 661 1025 727">MOSFET soldered traditionally on the PCB but more efficient cooling from the top</p> | <p data-bbox="1302 276 1657 312">Power chip embedding</p>  <p data-bbox="1193 607 1769 705">Chip embedding technology (jointly with Schweizer Electronic): Infineon MOSFET integrated within the PCB</p> |
| Customer benefits | <p data-bbox="397 798 1025 831">Significantly improved thermal management</p> | <p data-bbox="1155 760 1837 863">Increase of power density, energy efficiency and reliability: up to 60% performance improvement compared to traditionally designed system</p> |
| Success | <p data-bbox="397 907 1025 972">Major European tier-1 awarded Infineon with a triple-digit million Euro design-win</p> | <p data-bbox="1193 907 1798 940">Vitesco first player to adopt the technology</p> |

Besides main inverter and on-board charger, battery management is a good example for Infineon's system solution competence

Infineon offers basically all components of a complete battery management system (BMS)



To meet best cost-performance ratio in xEV drivetrain, IGBT and SiC technologies will co-exist

Selected examples of IGBT versus SiC

Example: All-wheel drive BEV



Focus on {
Range: **SiC**
Cost {
Large battery: **SiC**
Small battery: **IGBT**

Focus on cost only: **IGBT**

Example: Axle split PHEV



Focus on cost only: **IGBT**

Focus on range: **Internal Combustion Engine**

Technology and market development

Choice of power semiconductor technology in main inverter

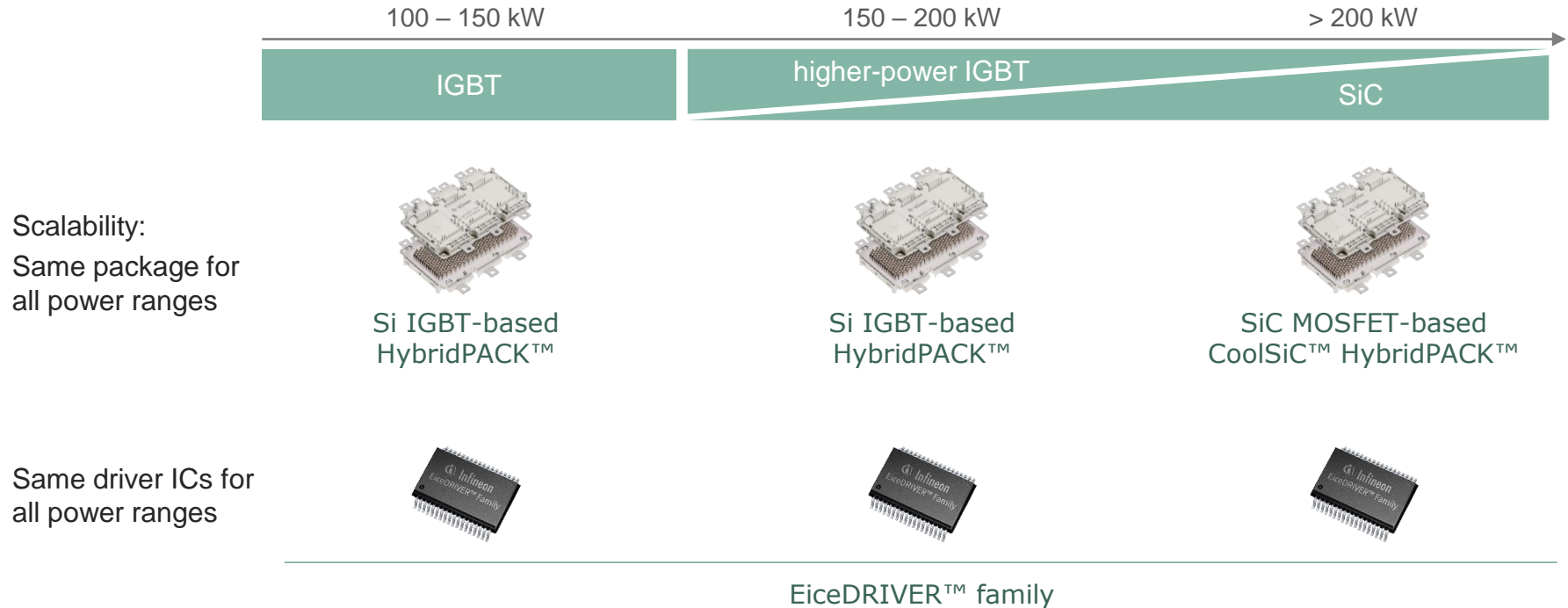
- › More and more OEMs are considering SiC as an alternative to IGBTs
- › OEMs' choice of main inverter technology depends on the choice of
 - › range versus cost, and
 - › size/cost of the battery

Market development

- › Higher-volume platforms to be launched in ~2025 are being awarded over the next quarters
- › To address range anxiety, OEMs shift focus to sufficient reach (for mid- to high-end cars preferably)
- › To improve their CO₂ footprint online retailers need to operate fully electrified delivery vehicles

When OEMs will introduce SiC-based car models to increase their fleet offering, Infineon can leverage its huge IGBT customer base

Infineon offers a seamless and cost-effective upgrade path across the entire power range



Infiniteon has an excellent position to win upcoming SiC-based xEV platforms



Infineon's leverage in SiC

Technology leverage

- › Infineon is addressing the xEV market with its growing portfolio of SiC-based components optimized for automotive applications

Leverage of customer base

- › Infineon's large IGBT customer base is an essential asset for the transition to SiC

Scalability

- › Scalable portfolio of Infineon allows for easy and seamless upgrade from IGBT-based inverters to SiC-based inverters
- › Existing customers can beef-up their platform performance while sticking to the same module form factor

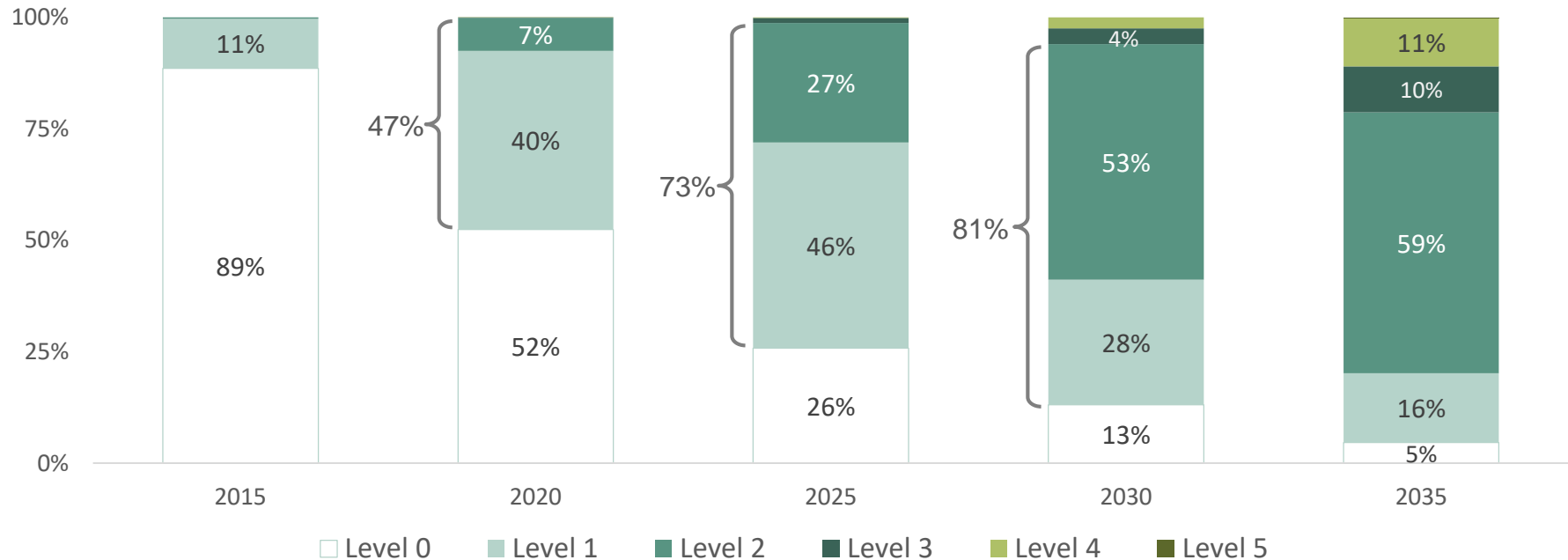


Automated Driving



The growth of L1/L2/L2+ is the main driver of ADAS semi content until 2030; low near-term impact from L3/L4/L5

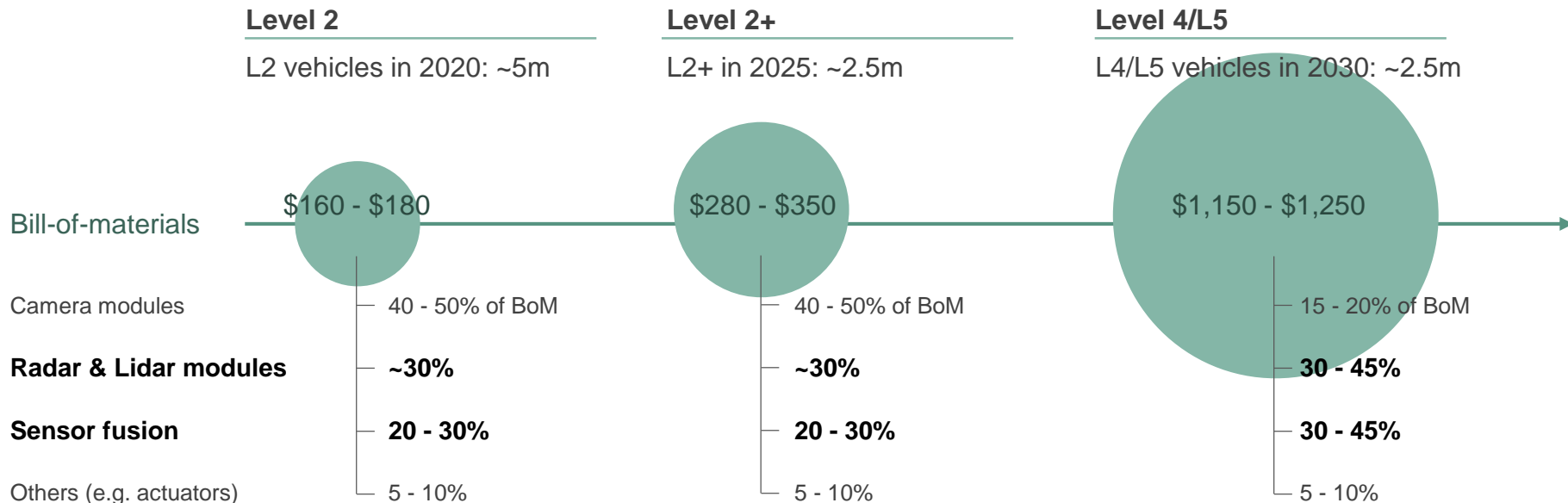
Car production by degree of automation



Source: Strategy Analytics: *Metrix Live*. December 2019; L2 includes L2 and L2+

Radar/Lidar modules and sensor fusion will grab the lion's share of semiconductor BoM in ADAS/AD-equipped cars

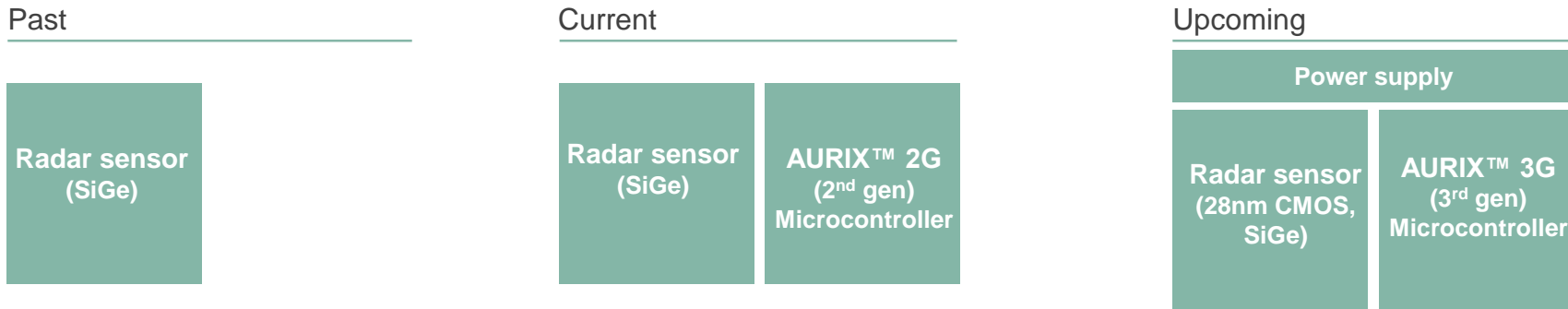
Incremental average semiconductor content per car by level of automation at the given years



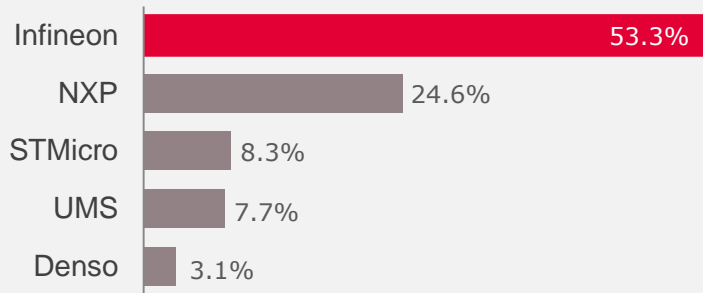
Source: Strategy Analytics: *Automated Driving Semiconductor Market Estimate*. August 2020; Infineon
BoM contains all type of semiconductors (e.g. radar modules include μ C); sensor fusion does not include memory.
BoM are projected figures for the respective time frame.

Infiniteon will roughly double its BoM content in upcoming high-volume radar systems by offering an optimized system portfolio

Infiniteon's increasing offering in 77 GHz radar system solutions



2019 automotive radar sensor IC market (77 / 24 GHz)

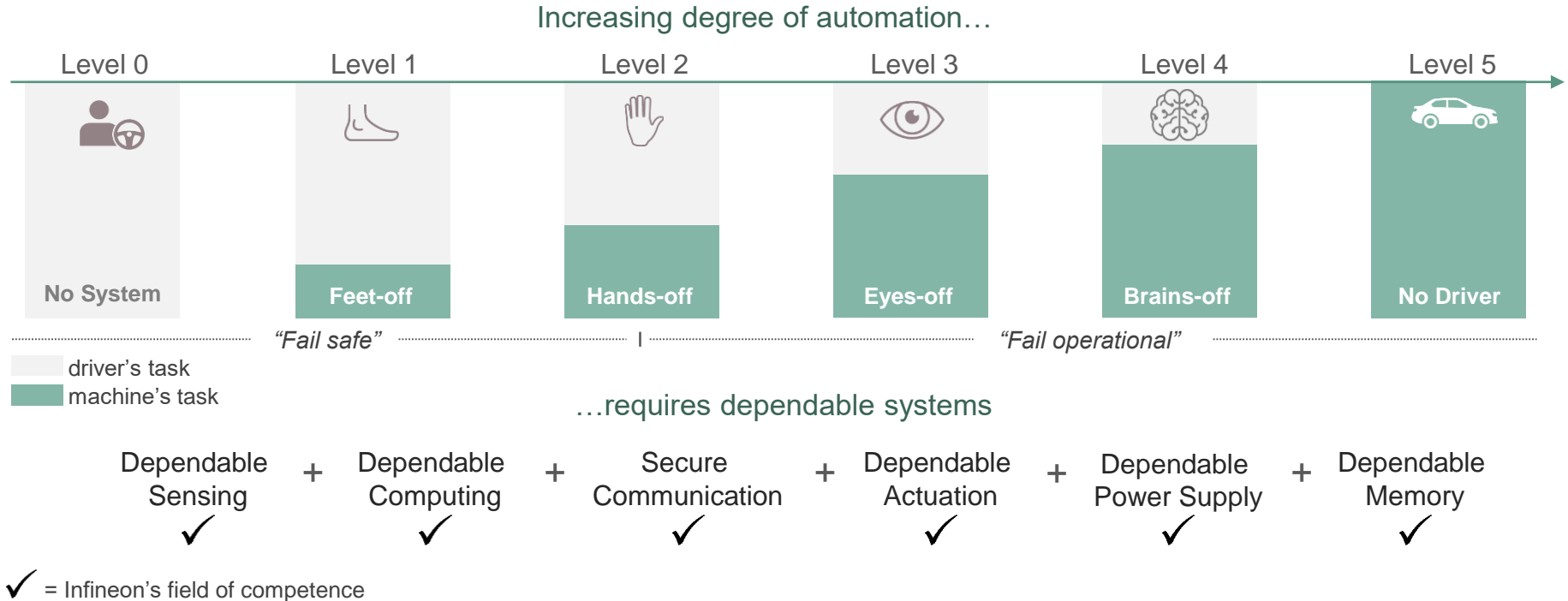


- › Dedicated AURIX™ microcontrollers with hardware-coded radar signal preprocessing will roughly double Infineon's semiconductor content

- › System-level offering combining radar sensor ICs, microcontrollers and power supply
- › Major advantages for customers:
 - interoperability
 - shorter development time
 - faster time-to-market

Higher levels of automated driving require trust via solutions that one can depend on

The need for dependable systems per degree of automation

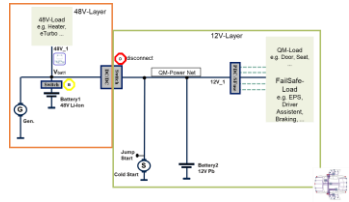


The need for dependability will drive demand for semiconductors; example: intelligent power switches

Example: Power distribution architecture in a car by degree of automation

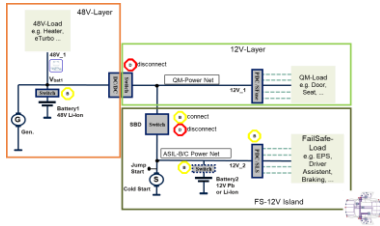
Level 2

Today's
reference architecture



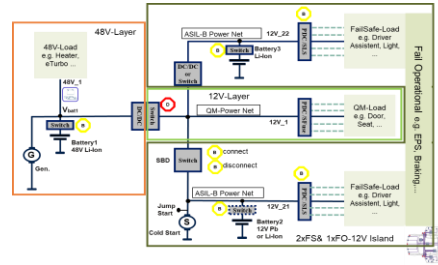
Level 2+

Dedicated protected
branches for critical loads



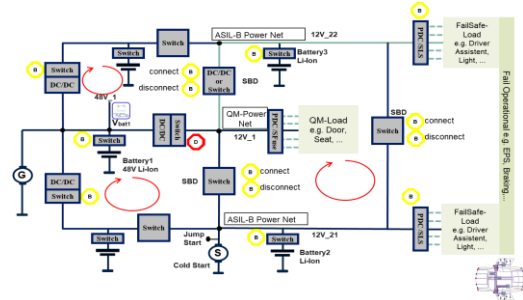
Level 3

Redundancy for critical loads



Level 4/5

Sophisticated “dependability” concept



1x

1.3x

2x

>3x

Number of intelligent power switches

Infiniteon's NOR Flash business is another beneficiary of the need for dependability



Structural growth drivers for NOR Flash in general

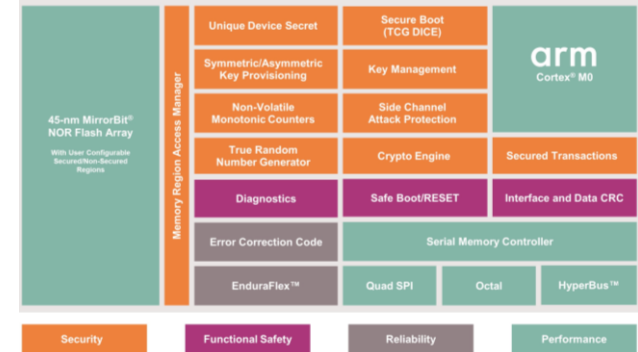
- › increasing system complexity drives demand for higher off-chip code storage
- › growing number of applications based on high-performance processing units:
 - › code and parameter storage for MCUs, GPUs, MPUs, and other SoCs
 - › configuration data for FPGAs

Automotive applications of NOR Flash

- › ADAS/AD
- › instrument clusters
- › navigation systems
- › Software-over-the-air (SOTA) updates

Infiniteon's unique offering: Semper™ Secure NOR Flash

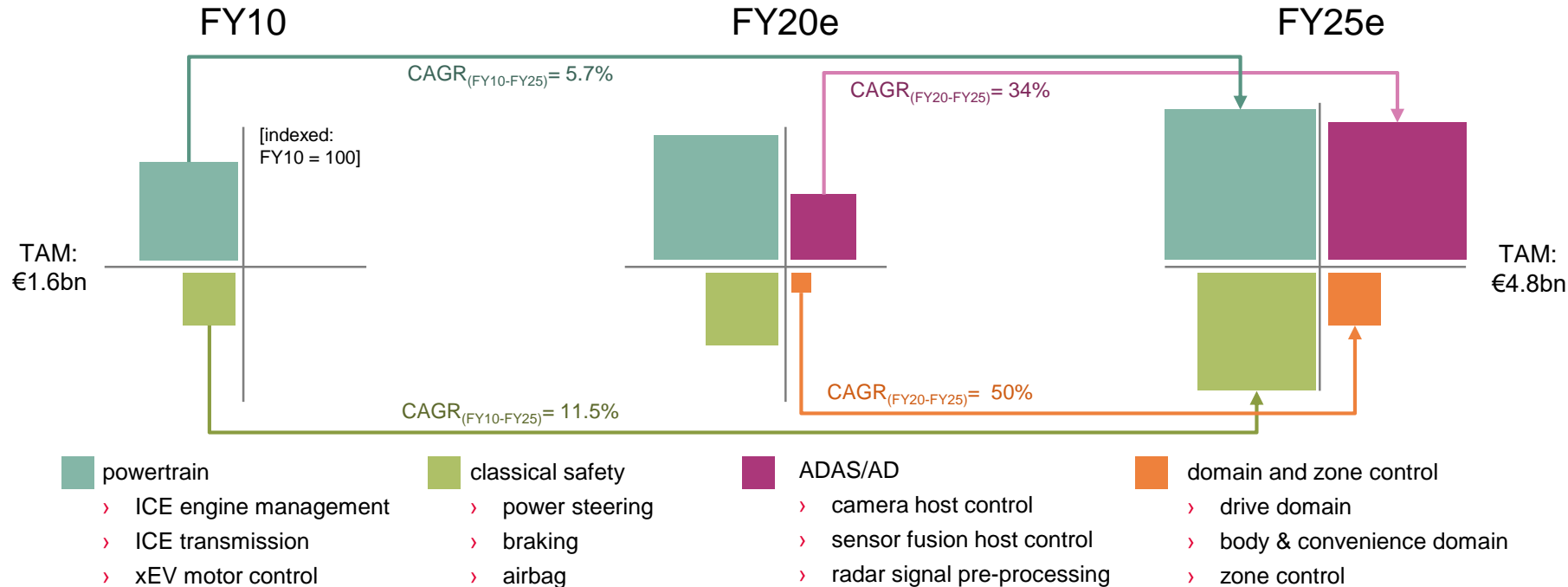
- › Infineon Semper™ Secure NOR Flash is the first memory solution to combine security and functional safety in a single NOR Flash device
- › Infineon Semper™ Secure NOR Flash delivers the security, safety, and reliability required for the most advanced connected automotive systems



The Infineon AURIX™ μ C family has become the first-choice automotive architecture for high-growth and safety-critical applications



Infineon AURIX™ revenue development over time



Source: Infineon; Strategy Analytics: *Automotive Semiconductor Demand Forecast*. February 2020. Covering Infineon target markets; excl. body, comfort, infotainment.

Strong microcontroller footprint in next-generation high-volume platforms



OEM platform #1:

- › 14 MCUs (+ NOR Flash + Wi-Fi)
- › start of production: end of CY20

| | | | |
|---|---|--|---|
| Engine control module AURIX™ TC38x | Braking AURIX™ TC39x | AD fusion standard AURIX™ TC39x | Instrument cluster NOR Flash S26KS512 |
| Drivetrain control module AURIX™ TC23x | Airbag AURIX™ TC23x | AD fusion high-end AURIX™ TC39x | Infotainment module 89359 (Wi-Fi / Bluetooth) |
| Transmission control module AURIX™ TC27x | Electric power steering AURIX™ TC27x | Central AD decision module AURIX™ TC39x | Central AD module NOR Flash S70FL01G S25FL512 S25FS512 |
| Automatic gear shifter module AURIX™ TC23x | Automatic sway bar AURIX™ TC23x | Secure gateway module AURIX™ TC39x | |
| Electronic slip differential AURIX™ TC23x | Map driver assistance AURIX™ TC39x | | |

Infineon heritage

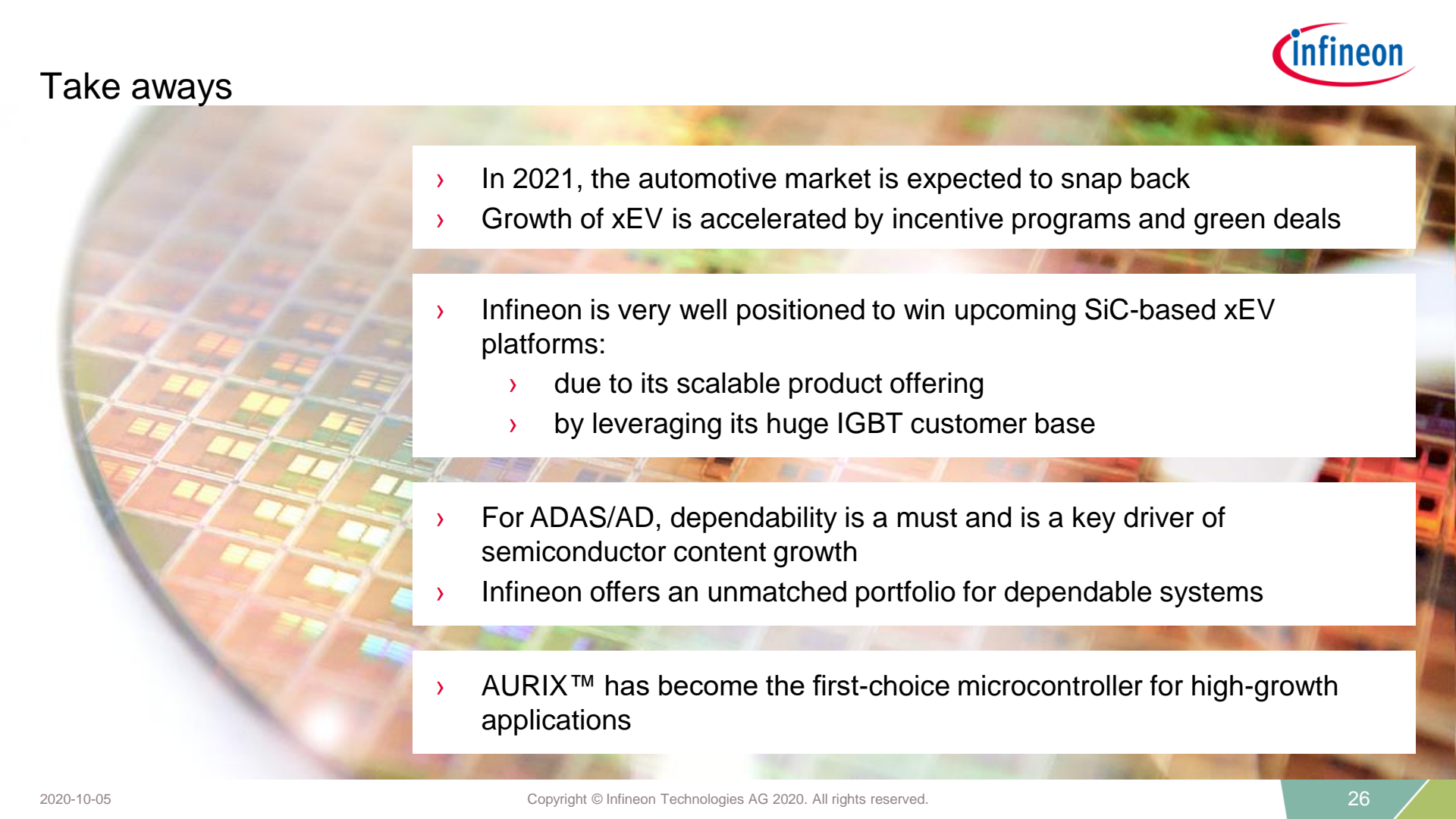
Cypress heritage

OEM platform #2:

- › 20 MCUs
- › start of production: CY22

| | | | |
|---|---|---|---|
| Engine management AURIX™ TC38x | Braking AURIX™ TC38x | AD fusion standard AURIX™ TC39x | Cluster TFT module FCR4 MB9DF125 |
| Diesel engine management AURIX™ TC39x | Airbag AURIX™ TC37x | AD fusion high-end AURIX™ TC39x | 8" rear-seat entertainment TrueTouch TMA78 |
| Transmission control module AURIX™ TC38x | Electric power steering AURIX™ TC36x | Front camera AURIX™ TC37x | 10" navigation module TrueTouch TMA1036 |
| Inverter PHEV AURIX™ TC38x | Suspension CVC AURIX™ TC38x | Radar domain processing AURIX™ TC39x | Climate, gearshift MMI FR CY91xxx |
| Door module FR MB91520 | Alarm system module FR MB91F520 | Digital instrument cluster Traveo I S6J332 | Head light module FR MB91F525 |

Take aways

- 
- A close-up, slightly blurred image of a semiconductor wafer, showing a grid of square dies with various colors (yellow, orange, green, blue) and intricate patterns. The wafer is circular and occupies the left and bottom portions of the slide.
- › In 2021, the automotive market is expected to snap back
 - › Growth of xEV is accelerated by incentive programs and green deals
 - › Infineon is very well positioned to win upcoming SiC-based xEV platforms:
 - › due to its scalable product offering
 - › by leveraging its huge IGBT customer base
 - › For ADAS/AD, dependability is a must and is a key driver of semiconductor content growth
 - › Infineon offers an unmatched portfolio for dependable systems
 - › AURIX™ has become the first-choice microcontroller for high-growth applications



Part of your life. Part of tomorrow.

Glossary

| | |
|-------|--|
| AC-DC | alternating current - direct current |
| AD | automated driving |
| ADAS | advanced driver assistance system |
| BEV | battery electric vehicle |
| BMS | battery management system |
| BoM | bill of material |
| CAN | controller area network |
| CMOS | complementary metal-oxid semiconductor |
| CPU | central processing unit |
| CVC | California vehicle code |
| DC-DC | direct current - direct current |
| ECU | electronic control unit |
| EPS | electric power steering |
| EV | electric vehicle |
| FCEV | fuel cell electric vehicle |
| FHEV | full-hybrid electric vehicle |
| FPGA | field programmable gate array |
| GaN | gallium nitride |
| GPU | graphics processing unit |
| HSM | hardware security module |
| HV | high-voltage |
| HW | hardware |
| IC | integrated circuit |
| ICE | internal combustion engine |
| IGBT | insulated gate bipolar transistor |
| IVN | in-vehicle networking |
| MCU | microcontroller unit |
| μC | microcontroller |

| | |
|-------------------|--|
| MHEV, mild-hybrid | mild-hybrid electric vehicle; vehicles using start-stop systems, recuperation, DC-DC conversion, e-motor |
| micro-hybrid | vehicles using start-stop systems and limited recuperation |
| mild-hybrid | vehicles using start-stop systems, recuperation, DC-DC conversion, e-motor |
| MOSFET | metal-oxide silicon field-effect transistor |
| MPU | microprocessor unit |
| NEDC | new European drive cycle |
| OBC | on-board charger |
| OEM | original equipment manufacturer |
| PCB | printed circuit board |
| PHEV | plug-in hybrid electric vehicle |
| PMIC | power management IC |
| PT | powertrain |
| RF | radio frequency |
| RoW | rest of world |
| Si | silicon |
| SiC | silicon carbide |
| SiGe | silicon germanium |
| SoC | system-on-chip |
| SOTA | software over-the-air |
| SW | software |
| TAM | total addressable market |
| ToF | time-of-flight |
| V2X | vehicle-to-everything communication |
| xEV | all degrees of vehicle electrification (EV, FHEV, HEV, PHEV) |

Disclaimer

Disclaimer

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Peter Schiefer

Division President Automotive



- › since 2016: Division President Automotive
- › Sep 2012: Head of Infineon worldwide Operations, responsible for chip production, assembly and testing, as well as process technology development, supply chain and purchasing
- › Jan 2012: Division President Power Management & Multimarket
- › since 2018: Member and Vice Chairman of the Board of Directors of the JV SIAPM (SAIC Infineon Automotive Power Modules (Shanghai) Co. Ltd.)
- › 2013 – 2016: Member of the Supervisory Board of Infineon Technologies Austria
- › since 2012: Member of the Supervisory Board of Infineon Technologies Dresden

- › Peter Schiefer was born in Munich, Germany, in 1965. He holds a Diploma in Electrical Engineering from the University of Applied Sciences in Munich.
- › He joined Infineon (Siemens AG until 1999) in 1990.